

PATENT ASSIGNMENT

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| SUBMISSION TYPE: | NEW ASSIGNMENT |
| NATURE OF CONVEYANCE: | ASSIGNMENT |
| CONVEYING PARTY DATA | |
| Name | Execution Date |
| SanDisk Corporation | 04/04/2011 |
| RECEIVING PARTY DATA | |
| Name: | SanDisk Technologies Inc. |
| Street Address: | 6900 North Dallas Parkway |
| Internal Address: | Two Legacy Town Center |
| City: | Plano |
| State/Country: | TEXAS |
| Postal Code: | 75024 |
| PROPERTY NUMBERS Total: 1 | |
| Property Type | Number |
| Patent Number: | 7663216 |
| CORRESPONDENCE DATA | |
| Fax Number: | (408)801-8512 |
| <i>Correspondence will be sent via US Mail when the fax attempt is unsuccessful.</i> | |
| Phone: | 4088012863 |
| Email: | simona.benjamin@sandisk.com |
| Correspondent Name: | SanDisk Corporation |
| Address Line 1: | 601 Mccarthy Boulevard |
| Address Line 2: | Patent Department/Simona Benjamin |
| Address Line 4: | Milpitas, CALIFORNIA 95035 |
| ATTORNEY DOCKET NUMBER: | SDK0681.000US |
| NAME OF SUBMITTER: | Simona Benjamin |
| Total Attachments: 5 source=Assignment 67#page1.tif source=Assignment 67#page2.tif source=Assignment 67#page3.tif source=Assignment 67#page4.tif source=Assignment 67#page5.tif | |

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ASSIGNMENT

WHEREAS, SanDisk Corporation, a Delaware corporation, doing business at 601 McCarthy Boulevard, Milpitas, CA 95035 (hereinafter referred to as **ASSIGNOR**), holds right, title and interest throughout the world in and to the patents and patent applications set forth in the attached Exhibit A, together with all divisions, continuations, or continuations-in-part thereof, and all patents issuing thereon including reissues, renewals, substitutions, re-examinations and extensions thereof, and any and all corresponding foreign patents and patent applications (hereinafter referred to as, collectively, **THE ASSIGNED PATENT RIGHTS**);

WHEREAS, SanDisk Technologies Inc., a Texas corporation, doing business at Two Legacy Town Center, 6900 North Dallas Parkway, Plano, Texas 75024, (hereinafter referred to as **ASSIGNEE**), is desirous of acquiring the full and exclusive right, title and interest in **THE ASSIGNED PATENT RIGHTS**;

NOW, THEREFORE, for good and valuable consideration, the receipt of which is hereby acknowledged, **ASSIGNOR** hereby assigns, transfers and conveys unto the said **ASSIGNEE**, and **ASSIGNEE** accepts, all of **ASSIGNOR**'s right, title and interest throughout the world in and to **THE ASSIGNED PATENT RIGHTS** and to all Letters Patent or applications or similar legal protection, not only in the United States and its territorial possessions, but in all countries foreign thereto to be obtained for **THE ASSIGNED PATENT RIGHTS**, and to any continuation, division, renewal, substitute or reissue thereof or any legal equivalent thereof in the United States or a foreign country for the full term or terms for which the same may be granted, including all priority rights under the International Convention; and **ASSIGNOR** hereby authorizes and requests the United States Commissioner of Patents and Trademarks and any officials of foreign countries whose duty it is to issue patents on applications as aforesaid, to issue all patents for **THE ASSIGNED PATENT RIGHTS** to **ASSIGNEE** in accordance with the terms of this **ASSIGNMENT** but subject to reserved rights including but not limited to those previously retained by, granted to, or owned by, the United States government, educational institutions or both and hereby transfers and conveys all rights of action, power and benefit belonging to or accruing from **THE ASSIGNED PATENT RIGHTS** including the right to undertake proceedings to recover past and future damages and claim all other relief in respect of any acts of infringement thereof whether such acts shall have been committed before or after the date of this assignment.

No other rights, immunities, or licenses, including, without limitation, any rights to any intellectual property owned, controlled or licensable by **ASSIGNOR** are granted or assigned to **ASSIGNEE** under this **ASSIGNMENT**, either expressly or by implication, estoppel, or otherwise, other than the rights expressly recited herein.

ASSIGNOR hereby covenants that no assignment, sale, agreement or encumbrance has been or will be made or entered into which would knowingly conflict with this Agreement;

ASSIGNOR further covenants that **ASSIGNEE** will, upon its lawful request, reasonably be provided with all pertinent facts and documents relating to **THE ASSIGNED PATENT RIGHTS** and legal equivalents as may be known and reasonably accessible to **ASSIGNOR** and that **ASSIGNOR** will testify as to the same in any administrative contest or litigation related thereto and will promptly execute and deliver to **ASSIGNEE** or its legal representative any and all papers, instruments or affidavits required to apply for, obtain, maintain, issue and enforce **THE ASSIGNED PATENT RIGHTS** and said equivalents in the United States or in any foreign country, which may be necessary or desirable to carry out the purposes thereof.

IN TESTIMONY WHEREOF, I hereunto set my hand as of the date indicated below.

SANDISK CORPORATION

Dated: 4th April 2011

Judy Bruner
Name: Judy Bruner
Title: EVP 2nd CFO

STATE OF California)
COUNTY OF Santa Clara) ss.

On this 4th day of April, 2011, before me Averil Branwen Watan (Notary Public), the undersigned Notary Public, personally appeared Judy Bruner,

who proved to me on the basis of satisfactory evidence to be the person(s) whose name(s) is/are subscribed to the within instrument and acknowledged to me that he/she/they executed the same in his/her/their authorized capacity(ies), and that by his/her/their signature(s) on the instrument the person(s), or the entity upon behalf of which the person(s) acted, executed the instrument.

I certify under PENALTY OF PERJURY under the laws of the State of California that the foregoing paragraph is true and correct.

WITNESS my hand and official seal.



Signature: Averil Watan
Signature of Notary Public

We accept the Assignment

SANDISK TECHNOLOGIES INC.

Dated: 4/4/11

James F. Brelsford
Name: James F. Brelsford
Title: President and Secretary

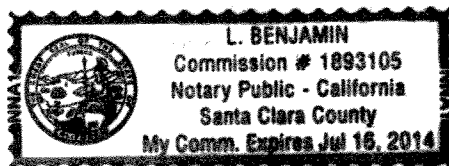
STATE OF California)
COUNTY OF Santa Clara) ss.

On this 4 day of April, 2011, before me L. Benjamin, the undersigned Notary Public, personally appeared JAMES F. BRELSFORD

who proved to me on the basis of satisfactory evidence to be the person(s) whose name(s) is/are subscribed to the within instrument and acknowledged to me that he/she/they executed the same in his/her/their authorized capacity(ies), and that by his/her/their signature(s) on the instrument the person(s), or the entity upon behalf of which the person(s) acted, executed the instrument.

I certify under PENALTY OF PERJURY under the laws of the State of California that the foregoing paragraph is true and correct.

WITNESS my hand and official seal.



Signature: L. Benjamin
Signature of Notary Public

Exhibit A

| FILE # | INVENTORS | TITLE | COUNTRY | STATUS | SER # | FILING DATE | PAT # | ISSUE DATE |
|---------------|--|---|---------|-----------|----------|-------------|---------|------------|
| SDK0677.001US | Christina Day, Peter Galat, Robert C Miller | FLASH MEMORY CARD WITH TRANSLUCENT COVER | US | Issued | 29244040 | 2-Dec-05 | D554123 | 30-Oct-07 |
| SDK0678.000US | Emilio Yero | Cycle count storage methods | US | Issued | 11404672 | 13-Apr-06 | 7451264 | 11-Nov-08 |
| SDK0678.001US | Emilio Yero | Cycle count storage systems | US | Issued | 11404454 | 13-Apr-06 | 7467253 | 16-Dec-08 |
| SDK0679.000US | Raul-Adrian Cernea, Yan Li | Use of Data Latches in Multi-Phase Programming of Non-Volatile Memories | US | Issued | 11097517 | 1-Apr-05 | 7158421 | 2-Jan-07 |
| SDK0679.001US | Yan Li, Raul-Adrian Cernea | Use of Data Latches in Multi-Phase Programming of Non-Volatile Memories | US | Issued | 11566583 | 4-Dec-06 | 7508721 | 24-Mar-09 |
| SDK0680.000US | Reuven Elhamias, Vivek Mani, Niv Cohen | System and method for write failure recovery | US | Issued | 11397416 | 3-Apr-06 | 7835518 | 16-Nov-10 |
| SDK0681.000US | Cheeman Yu, Chih Chin Liao, Hem Takiar | HIGH DENSITY THREE DIMENSIONAL SEMICONDUCTOR DIE PACKAGE | US | Issued | 11264889 | 2-Nov-05 | 7663216 | 16-Feb-10 |
| SDK0681.001US | Cheeman Yu, Chih Chin Liao, Hem Takiar | HIGH DENSITY THREE DIMENSIONAL SEMICONDUCTOR DIE PACKAGE | US | Published | 12648697 | 29-Dec-09 | | |
| SDK0682.000US | Raul-Adrian Cernea, Siu Lung Chan | Non-Volatile Memory and Method with Compensation for Source Line Bias Errors | US | Issued | 11097038 | 1-Apr-05 | 7173854 | 6-Feb-07 |
| SDK0682.001US | Raul-Adrian Cernea, Siu Lung Chan | Non-Volatile Memory and Method with Control Gate Compensation for Source Line Bias Errors | US | Issued | 11097502 | 1-Apr-05 | 7170784 | 30-Jan-07 |
| SDK0682.002US | Raul-Adrian Cernea, Siu Lung Chan | Non-Volatile Memory and Method with Compensation for Source Line Bias Errors | US | Issued | 11624617 | 18-Jan-07 | 7391645 | 24-Jun-08 |
| SDK0682.003US | Raul-Adrian Cernea, Siu Lung Chan | Non-Volatile Memory and Method with Control Gate Compensation for Source Line Bias Errors | US | Issued | 11624627 | 18-Jan-07 | 7391646 | 24-Jun-08 |
| SDK0682.004US | Raul-Adrian Cernea, Siu Lung Chan | Non-Volatile Memory and Method with Control Gate Compensation for Source Line Bias Errors | US | Issued | 12143015 | 20-Jun-08 | 7499324 | 3-Mar-09 |
| SDK0683.000US | Emilio Yero, Yan Li | Use of Data Latches in Cache Operations of Non-Volatile Memories | US | Issued | 11097590 | 1-Apr-05 | 7206230 | 17-Apr-07 |
| SDK0683.001US | Yan Li, Emilio Yero | Use of Data Latches in Cache Operations of Non-Volatile Memories | US | Issued | 11619513 | 3-Jan-07 | 7577037 | 18-Aug-09 |
| SDK0683.002US | Emilio Yero, Yan Li | Use of Data Latches in Cache Operations of Non-Volatile Memories | US | Allowed | 12495200 | 30-Jun-09 | | |
| SDK0684.001US | Gidon Elazar, Dan Harkabi, Nehemiah Weingarten | Apparatus for transferring licensed digital content between users | US | Published | 11531455 | 13-Sep-06 | | |
| SDK0686.000US | Masaaki Higashitani | Method of Forming Low Resistance Void-Free Contacts | US | Issued | 11296022 | 6-Dec-05 | 7615448 | 10-Nov-09 |
| SDK0686.001US | Masaaki Higashitani | Low Resistance Void-Free Contacts | US | Issued | 11296235 | 6-Dec-05 | 7737483 | 15-Jun-10 |
| SDK0689.000US | Masaaki Higashitani | Methods of Forming Flash Devices With Shared Word Lines | US | Issued | 11316474 | 21-Dec-05 | 7655536 | 2-Feb-10 |
| SDK0689.001US | Masaaki Higashitani | Flash Devices With Shared Word Lines | US | Issued | 11316654 | 21-Dec-05 | 7495294 | 24-Feb-09 |
| SDK0689.002US | Masaaki Higashitani | Methods of Forming Flash Devices With Shared Word Lines | US | Published | 12641113 | 17-Dec-09 | | |
| SDK0691.000US | Siu Lung Chan | Methods for Improved Program-Verify Operations in Non-Volatile Memories | US | Issued | 11323596 | 29-Dec-05 | 7224614 | 29-May-07 |
| SDK0691.001US | Siu Lung Chan | Non-Volatile Memory With Improved Program-Verify Operations | US | Issued | 11323577 | 29-Dec-05 | 7310255 | 18-Dec-07 |
| SDK0691.002US | Siu Lung Chan | Methods for Improved Program-Verify Operations in Non-Volatile Memories | US | Issued | 11753327 | 24-May-07 | 7447081 | 4-Nov-08 |
| SDK0691.003US | Siu Lung Chan | Non-Volatile Memory With Improved Program-Verify Operations | US | Issued | 11955624 | 13-Dec-07 | 7609556 | 27-Oct-09 |